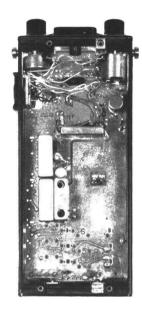


# MASTR® Personal

SYSTEMS BOARD AND CASE ASSEMBLY 19D417330G8



# **SPECIFICATIONS** \*

MODEL NUMBERS 19D417330G8

CONTROLS

450-470 MHz

Volume ON-OFF Switch

Squelch Control

Six-Frequency Selector Switch

PTT Switch

Tone Option Switch

Collapsible Antenna

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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### DESCRIPTION

System Board A707 provides system interfacing between the transmitter, receiver, tone options and operating controls in the 450-470 MHz, six frequency, local operated MVP, PY Series. The system board contains transmitter oscillator modules A5 through A10. Other modules on the system board are receiver oscillator modules A11 and A12, audio amplifier module A1, 5.4 Volt regulator module A2, compensator module A3, and modulator module A4. The system board also contains system relay K1 and audio and DC switching circuits.

### CIRCUIT ANALYSIS

#### AUDIO SWITCHING

Audio switching for local speaker/microphone LS1 is controlled by forward biasing diode CR5 (See Figure 1). Pressing PTT switch S701 causes the PTT circuit to complete the conduction path of CR5 to system ground. Pressing S701 also causes system relay K1 to apply bias voltage to the anode of CR5. Audio from the local speaker/microphone is then applied through CR5 to the input of transmitter audio module A1.

Receiver audio is connected directly to the internal speaker/microphone.

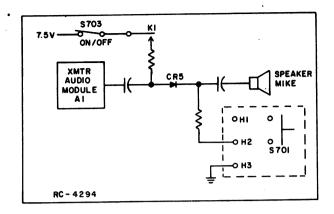


Figure 1 - Audio Switching

## DC SWITCHING

Operation of the system relay, keyed locally, is controlled by diode CR2 and PTT circuit A705 (See Figure 2). Pressing PTT switch S701 causes the PTT circuit to complete the conduction path of K1 through CR2 to system ground. Completing the conduction path energizes K1 to switch the battery voltage to the transmitter audio and regulator module. Energizing K1 also connects the transmitter output to the antenna.

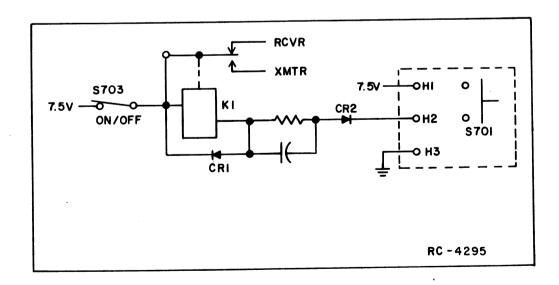


Figure 2 - DC Switching

### PTT Switch (A705)

Solid state PTT switch S701 forward biases diodes CR2 and CR5 to energize relay K1, keying the radio and applying audio from the local speaker/microphone to the input of the transmitter audio module.

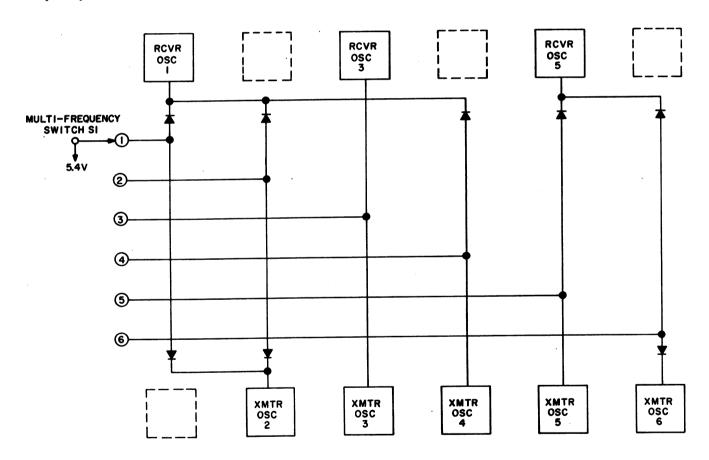
When S701 is pressed, NPN transistor Q1 of A705 conducts. Transistor Q1 conducting, provides a conduction path to ground for diode CR2. Relay K1 is energized and the radio is keyed.

#### REPEATING OSCILLATOR MODULES

Both the transmitter and receiver can be adapted to repeat the use of the same frequency without the use of additional Oscillator Modules. The Oscillator Module is replaced by a diode, allowing the frequency selector switch to have the same frequency on one or more switch positions even though only one Oscillator Module is used for each of the repeated channels. A typical diagram with repeated Oscillator Modules is shown in Figure 3.

Complete instructions for multi-frequency modifications are contained in the Multi-Frequency Modification diagram (see Table of Contents).

For radios equipped with Channel Guard, Type 90 Encoders/Decoders or Type 99 Decoders, repeating Oscillator Modules also permit switching or disabling tones on the same RF frequency with the multi-frequency switch. Also the tone and RF frequency can be changed at the same time.



RC-2748

Figure 3 - Repeating Oscillator Modules

GENERAL ELECTRIC COMPANY • MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS • LYNCHBURG, VIRGINIA 24502 USA



CRI, CR5

CR6, CVI

# SOLDER SIDE

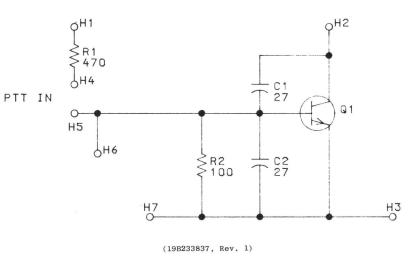


# LEAD IDENTIFICATION FOR Q1

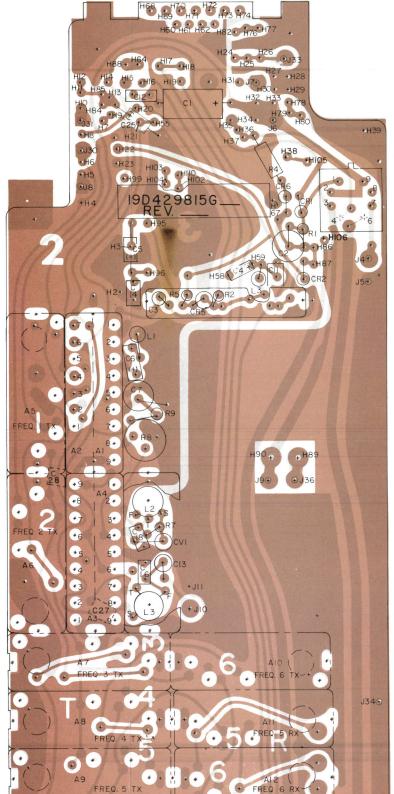
A 705

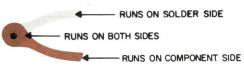


(19B233822, Rev. 0) (19A143811, Sh. 1, Rev. 0) (19A143811, Sh. 2, Rev. 0)



ALL RESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K-1000 OHMS OR MEG-1,000,000 OHMS. CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF-MICROFARADS. INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH-MILLIHENRYS OR H-HENRYS.





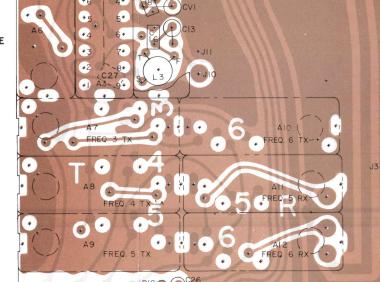
LEAD FORMING FOR

C6, C6

C26

CR2

C3



# OUTLINE DIAGRAM

450—470 MHz SYSTEM BOARD

(19D429814, Sh. 2, Rev. 3) (19D429814, Sh. 3, Rev. 2)

(19D430207, Rev. 2)

Issue 1

⊕J34

H98 +

J36⊕ ⊕19

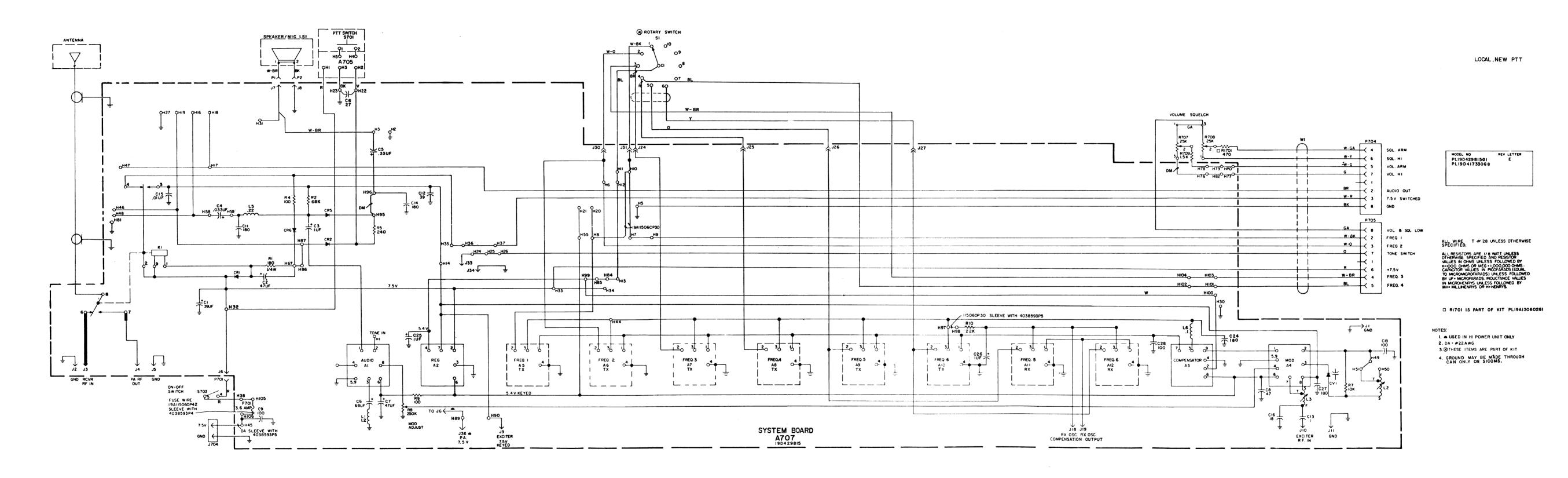
FREQ.6 FX

FREQ. 4 TX

FREQ.5 TX

€J27 €J26 €J25 €J24

(19D429814, Sh. 2, Rev. 3)



# SCHEMATIC DIAGRAM

450—470 MHz SYSTEM BOARD

## PARTS LIST

SYSTEM BOARD/CASE ASSEMBLY 19D417330G8 ISSUE 1

A705 PTT SWITCH BOARD 198233821G1	SYMBOL	GE PART NO.	DESCRIPTION
C1 and C2    19A700221P44   Ceramic: 27 pf ±5%, 100 VDCW.	A705		
19A134739P1   Silicon, PNP.			
Q1 19A134739P1 Silicon, PNP.	and	19A700221P44	Ceramic: 27 pf ±5%, 100 VDCW.
R1 3R151P471J Composition: 470 ohms ±5%, 1/8 w.  A707 SYSTEM BOARD 19D429815G1  A1 19C320062G1 Audio Transmitter.  A2 19C328070G1 Voltage Regulator.  A3 19C320061G3 Oscillator Compensator.  A4 19C320084G1 Modulator.  C1 5491674P30 Tantalum: 47 μf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 1.0 μf ±40-20%, 10 VDCW; sim to Sprague Type 162D.  C3 5491674P1 Tantalum: 0.033 μf ±10%, 20 VDCW; sim to Sprague Type 162D.  C4 5491674P51 Tantalum: 0.33 μf ±10%, 20 VDCW; sim to Kemet T3766733K.  C5 5491674P52 Tantalum: 0.33 μf ±10%, 20 VDCW; sim to Kemet T376673K.  C6 19C307102P19 Tantalum: 68 μf ±20%, 4 VDCW; sim to Kemet T376673K.  C7 5491674P42 Tantalum: 47 μf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf 19A700229P73 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf 19A700229P73 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 Pf 19A700221P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 Pf 19A700221P49 Ceramic: 180 pf ±10%, 100 VDCW.  C1 19A700221P49 Ceramic: 180 pf ±5%, 500 VDCW.  C1 19A700221P49 Ceramic: 180 pf ±5%, 500 VDCW.  C1 19A700221P49 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf 19A700221P48 Ceramic: 180 pf ±10%, 100 VDCW.  C1 19A700221P38 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf 19A700221P65 Ceramic: 180 pf ±5%, 100 VDCW, temp coef -80 Pf 19A700221P65 Ceramic: 180 pf ±5%, 100 VDCW, temp coef -1500 Pf M.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf 1500 Pf M.  C25 5491674P1 Tantalum: 1.0 μf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C2		TRANSISTORS
R1 3R151P471J Composition: 470 ohms ±5%, 1/8 w.  A707 SYSTEM BOARD 190429815G1  A1 19C320062G1 Audio Transmitter.  A2 19C328070G1 Voltage Regulator.  A3 19C320061G3 Oscillator Compensator.  A4 19C320084G1 Modulator.  C1 5491674P30 Tantalum: 39 µf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C3 5491674P51 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.  C5 5491674P51 Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S66GR.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 µf ±5%, 100 VDCW; temp coef -750 µf 19A70022P73 Ceramic: 100 µf ±5%, 100 VDCW; temp coef -750 µf 19A70022P73 Ceramic: 39 µf ±10%, 100 VDCW; temp coef -3300 µf 19A70021P49 Ceramic: 39 µf ±10%, 100 VDCW; temp coef -80 µf 19A70022P73 Ceramic: 180 µf ±10%, 100 VDCW.  C1 19A70022P73 Ceramic: 180 µf ±10%, 100 VDCW.  C1 19A70022P38 Ceramic: 180 µf ±20%, 50 VDCW.  C1 19A70022P765 Ceramic: 180 µf ±20%, 50 VDCW.  C1 19A70022P765 Ceramic: 180 µf ±20%, 50 VDCW.  C1 19A70022P765 Ceramic: 180 µf ±20%, 100 VDCW, temp coef -80 µf ±500 µPM.  C24 19A70022P773 Ceramic: 180 µf ±20%, 100 VDCW, temp coef -80 µf ±500 µPM.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	Ql	19A134739P1	Silicon, PNP.
A707  SYSTEM BOARD 190429815G1  A1 19C320062G1 A2 19C328070G1 A3 19C320061G3 A4 19C320084G1  C2 5491674P30  C3 5491674P42  C4 5491674P1  C5 5491674P1  C6 5491674P51  C7 Tantalum: 1.0 \( \mu f \) +40-20\( \mu f \) 10 VDCW; sim to Sprague Type 162D.  C6 5491674P51  C7 Tantalum: 0.033 \( \mu f \) 10\( \mu f \) 40-20\( \mu f \) 10 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19  C7 5491674P2  C8 19A70022BP3  C9 19A70022BP3  C1 19A70022P73  C1 19A70022P38  C1 19A70022P39  C1 19A70022P38  C1 19A70022P39  C1 19A70022P38  C1 19A70022P39  C1 19A70022P39  C2 2 19A70022P3  C2 2 19A70022P73  C2 3 3491674P1  Tantalum: 1.0 \( \mu f \) \( \mu			RESISTORS
A707  A1 19C320062G1	R1	3R151P471J	Composition: 470 ohms ±5%, 1/8 w.
19D429815G1  A1 19G320062G1 Audio Transmitter.  Voltage Regulator.  Oscillator Compensator.  A3 19G320084G1 Modulator.  C1 5491674P30 Tantalum: 39 μf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 47 μf ±20%, 6 VDCW; sim to Sprague Type 162D.  C3 5491674P1 Tantalum: 1.0 μf +40-20%, 10 VDCW; sim to Sprague Type 162D.  C4 5491674P51 Tantalum: 0.033 μf ±10%, 20 VDCW; sim to Sprague Type 162D.  C5 5491674P52 Tantalum: 0.33 μf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19G307102P19 Tantalum: 68 μf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 μf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 μf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf C1 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -750 Pf C1 19A70022P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 Pf C13 19A700023P13 Phenolic: 1.0 pf ±5%, 500 VDCW.  C14 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf C13 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf C14 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf C15 19A116192P1 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf C16 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 Pf C18 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 Pf M.  C25 5491674P1 Tantalum: 1.0 μf +40-20%, 10 VDCW; sim to Sprague Type 162D.	R2	3R151P101J	Composition: 100 ohms ±5%, 1/8 w.
19C328070G1   Voltage Regulator.   Oscillator Compensator.	A707		
19C320084G1	Al	19C320062G1	Audio Transmitter.
19C320084G1   Modulator.	A2	19C328070G1	Voltage Regulator.
C1 5491674P30 Tantalum: 39 µf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C3 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.  C4 5491674P51 Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 µf ±20%, 6 VDCW; temp coef -750 Pf 19A700226P65 Ceramic: 100 µf ±5%, 100 VDCW; temp coef -750 Pf 19A70022P73 Ceramic: 180 µf ±10%, 100 VDCW; temp coef -3300 PPM.  C12 19A700221P49 Ceramic: 39 µf ±10%, 100 VDCW; temp coef -80 µf 19A70022P73 Ceramic: 1.0 µf ±5%, 500 VDCW.  C15 19A116192P1 Ceramic: 1.0 µf ±20%, 50 VDCW.  C16 19A70022P78 Ceramic: 180 µf ±10%, 100 VDCW, temp coef -80 µf 19A70022P76 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P76 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P76 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P76 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 19A70022P77 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µf 1500 µf 15	A3	19C320061G3	Oscillator Compensator.
C1 5491674P30 Tantalum: 39 µf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C3 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.  C4 5491674P51 Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf 19A70022P73 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf 19A70022P73 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -300 Pf 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C12 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C13 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C14 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C15 19A116192P1 Ceramic: 1.0 pf ±5%, 500 VDCW.  C16 19A70022P785 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPf 19A70022P765 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPf 19A70022P765 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 PPf 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 PPM.  C25 3491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	A4	19C320084G1	Modulator,
C1 5491674P30 Tantalum: 39 µf ±20%, 10 VDCW; sim to Sprague Type 162D.  C2 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C3 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.  C4 5491674P51 Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf 19A70022P73 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf 19A70022P73 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -300 Pf 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C12 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C13 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C14 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C15 19A116192P1 Ceramic: 1.0 pf ±5%, 500 VDCW.  C16 19A70022P785 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPf 19A70022P765 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPf 19A70022P765 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 PPf 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 PPM.  C25 3491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.			QLD LQ LTDDS
Type 162D.  Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprag Type 162D.  Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf C10 19A700226P65 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf C11 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.  C12 19A70022P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 pf C13 19A70022P73 Ceramic: 1.0 pf ±5%, 500 VDCW.  C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 1.0 pf ±20%, 50 VDCW.  C16 19A70022P78 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPM.  C18 19A70022P765 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPM.  C24 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 PPM.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C1	5491674P30	Tantalum: 39 µf ±20%, 10 VDCW; sim to Sprague
Type 162D.  C4 5491674P51 Tantalum: 0.033 µf ±10%, 20 VDCW; sim to Kemet T376P33K.  C5 5491674P52 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pi C10 19A700226P55 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pi C11 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.  C12 19A700221P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 pf C13 19A700013P13 Phenolic: 1.0 pf ±5%, 500 VDCW.  C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 180 pf ±10%, 100 VDCW.  C16 19A700221P38 Ceramic: 180 pf ±10%, 50 VDCW.  C17 19A70022P65 Ceramic: 180 pf ±5%, 100 VDCW, temp coef -80 PPI C18 19A70022P65 Ceramic: 180 pf ±5%, 100 VDCW, temp coef -80 PPI C19 Tantalum: 100 µf ±40-20%, 100 VDCW.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C2	5491674P42	
T376P33K.  Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Kemet T376B334K020AS.  C6 19C307102P19 Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  C7 5491674P42 Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 µf ±5%, 100 VDCW; temp coef -750 µi condition of the coef type 162D.  C10 19A700226P65 Ceramic: 100 µf ±5%, 100 VDCW; temp coef -750 µi condition of the coef type 162D.  C11 19A700229P73 Ceramic: 180 µf ±10%, 100 VDCW; temp coef -80 µi condition of the coef type 19A700221P49 Ceramic: 39 µf ±10%, 100 VDCW; temp coef -80 µi condition of the coef type 19A70022P73 Ceramic: 1.0 µf ±5%, 500 VDCW.  C14 19A70022P73 Ceramic: 180 µf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 180 µf ±20%, 50 VDCW.  C16 19A70022P765 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -80 µi condition of the coef type 19A70022P73 Ceramic: 180 µf ±5%, 100 VDCW, temp coef -1500 µpm.  C24 19A70022P73 Ceramic: 180 µf ±10%, 100 VDCW.  Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	СЗ	5491674P1	
T376B334K020AS.  T376B334K020AS.  Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.  Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  Byfoo226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf 194700226P65 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pf 19470022P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -750 Pf 19470022P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 pf 19470022P49 Ceramic: 1.0 pf ±5%, 500 VDCW.  C12 19470022P49 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -80 pf 19470022P73 Ceramic: 180 pf ±10%, 100 VDCW.  C14 19470022P73 Ceramic: 180 pf ±20%, 50 VDCW.  C15 194716192P1 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPf 19470022P765 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19470022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -80 PPf 19470022P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 PPM.  C25 3491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C4	5491674P51	
Electronics S686R.  Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf	C5	5491674P52	
Type 162D.  C8 19A700226P53 Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pi C10 19A700226P65 Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 Pi C11 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.  C12 19A700221P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 PF C13 19A700013P13 Phenolic: 1.0 pf ±5%, 500 VDCW.  C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCW.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPI C18 19A70022P65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW, temp coef -1500 PPM.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C6	19C307102P19	Tantalum: 68 µf ±20%, 4 VDCW; sim to Corning Electronics S686R.
C10 19A700226P65	C7	5491674P42	Tantalum: 47 $\mu$ f $\pm 20\%$ , 6 VDCW; sim to Sprague Type 162D.
C11 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW; temp coef -300 PPM.  C12 19A700221P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 PF C13 19A700013P13 Phenolic: 1.0 pf ±5%, 500 VDCW.  C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCW.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPF C18 19A70022P765 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C8	19A700226P53	Ceramic: 47 pf ±5%, 100 VDCW; temp coef -750 Pf
-3300 PPM.  C12 19A700221P49 Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 pp  C13 19A700013P13 Phenolic: 1.0 pf ±5%, 500 VDCW.  C14 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCW.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPI  C18 19A70022P65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef  -1500 PPM.  C24 19A70022P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to  Sprague Type 162D.	C10	19A700226P65	Ceramic: 100 pf ±5%, 100 VDCW; temp coef -750 F
C13 19A700013P13 Phenolic: 1.0 pf ±5%, 500 VDCw.  C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCw.  C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCw.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCw, temp coef -80 PPI  C18 19A70022P765 Ceramic: 100 pf ±5%, 100 VDCw, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCw.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCw; sim to Sprague Type 162D.	C11	19A700229P73	
C14 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCW.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPR  C18 19A70022PF65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf ±40-20%, 10 VDCW; sim to Sprague Type 162D.	C12	19A700221P49	Ceramic: 39 pf ±10%, 100 VDCW; temp coef -80 pr
C15 19A116192P1 Ceramic: 0.01 µf ±20%, 50 VDCW.  C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPI  C18 19A700227P65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.	C13	19A700013P13	Phenolic: 1.0 pf ±5%, 500 VDCw.
C16 19A700221P38 Ceramic: 18 pf ±5%, 100 VDCW, temp coef -80 PPI C18 19A700227P65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM. C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW. C25 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.	C14	19A700229P73	Ceramic: 180 pf ±10%, 100 VDCW.
C18 19A700227P65 Ceramic: 100 pf ±5%, 100 VDCW, temp coef -1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCW.  C25 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.	C15	19A116192P1	1
-1500 PPM.  C24 19A700229P73 Ceramic: 180 pf ±10%, 100 VDCw.  C25 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.	C16	19A700221P38	
C25 5491674P1 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.	C18	19A700227P65	
and Sprague Type 162D.	C24	19A700229P73	Ceramic: 180 pf ±10%, 100 VDCw.
	and	5491674P1	Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D.

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SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
C27	19A700229P73	Ceramic: 180 pf ±10%, 100 VDCW.			JACKS AND RECEPTACLES		
C28	19A700229P65	Ceramic: 100 pf ±5%, 100 VDCW.	J704		See Mechanical Parts RC3744 items 57-61.		7150729P4
		DIODES AND RECTIFIERS	""				19A134457P1
CR1	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.		İ	PLUGS		
CR2	5494922P1	Silicon; sim to Type 1N456.	P701	19A115834P4	Contact, electrical: sim to AMP 2-332070-9.		
CR5	5494922P1	Silicon; sim to Type 1N456.	P704 and P705	19A116137P3	Socket, crystal: 8 contacts; sim to Cinch 133-98-92-061. (Part of WIA).		
CR6	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	P705			1	19A127319P1
CAI	5495769P9	Silicon, capacitive.	R707	19A116227P1	· · · · · · · · · · · · · · · · · · ·	2	4037064P18
					Resistor/Switch: variable, carbon film, 25K ohms ±20%, 1/8 w, (Includes S703), rotary, SPST, 3 amps at 125 VAC; sim to Mallory Type MZC.	3	4035630P1
F701	19A127884G1	Fuse Kit.	R708	19A116227P2	Variable, carbon film: 25K ohms ±20%, 1/8 w; sim	4	19B232784G2
		JACKS AND RECEPTACLES	P700	0015101507	to Mallory Type MZC.	5	N70BP703C6
Jl	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	R709 R1701	3R151P152J 3R152P471J	Composition: 1.5K ohms ±5%, 1/8 w.	6	19A137254P1
thru J5	13/11/33/04/1	Contract,   Contract   Contract	K1701	3813294713	Composition: 470 ohms ±5%, 1/4 w. (Part of Intrinsically Safe Kit 19A130602G1).	7 8	19A127802P1 19A116773P805
J6	19A116366P2	Contact, electrical: sim to Cambion 323301-03.			SWITCHES	9	19B227270G1
thru J8			S701		See Mechanical Parts RC3744 items 36-42.	10	19B227270G2
J9	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	8703		(Part of R707).	11	19D423170G1
thru Jll						12	NP280150P1
J18 thru	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	WIA	19C330826G2	Cable. (Includes P704 & 705).	13	NP280150P2
J21			W2B	19A144162G2	RF: (Specify length).	14	19B216858P1
J24 thru	19A116366P4	Contact, electrical: sim to Concord 10-891-1.				15	N681P5002C6
J27		10.001.1	1		ASSOCIATED ASSEMBLIES	16	NP270687
J30 and	19A116366P4	Contact, electrical: sim to Concord 10-891-1.			OSCILLATORS	17	19A134548P1
J31	19A116366P2	Contact, electrical: sim to Cambion 3233-01-03.			NOTE: When reordering, give GE Part Number and specify exact frequency needed.	18	
and J34	194110300F2	contact, creetitear.			specify exact frequency needed.	19	N170P9004C17
K1	19B209562P2	Hermetic sealed: between 45-100 ohms, 2 form C contacts, 5.0 VDC nominal, 1.0 w max operating; sim to GE 3SCS1002A2.	A5 thru A10 A11 and	4EG27A11	Transmitter Oscillator Module. Fx= $\frac{Fo}{24}$ Receiver Oscillator Module. Fx= $\frac{Fo-23}{21}$ MHz	20 21 22	19A127779G8 19A129651P1 19B216875P1
		INDUCTORS	A12			23	19B209548P1
Ll	19B209420P114	Coil, RF: 1.20 µh ±10%, 0.18 ohms DC res max; sim to Jeffers 4436-lK.			FRONT COVER ASSEMBLY 19C317416G9 LOW POWER	24 25	19C321437P1
L2	19A127798G1	Coil: 6.05-6.9 µh. Includes:			19C317416G10 HIGH POWER	26	19A115983P3
	19B209436P1	Tuning slug.			LOUDSPEAKERS	27	N509P606C
L3	19B219527G1	Coil. Includes:	LS1	19A134949P1	Permanent magnet: 2.00 inch, 8 ohms ±15% voice coil imp, 500 Hz ±50 Hz resonant; sim to Oaktron	28	19B219510P1
	19B209436P1	Tuning slug.			Sample No. T6703.	29	19A130397P1
IA.	19B219527G3	Coil. Includes:				30	19C317394P4
	19B209436P1	Tuning slug.	Pl	19A115834P4	Contact, electrical: sim to AMP 2-332070-9.	31	19A130993P1
L5	19B209420P105	Coil, RF: 220 µh ±10%; sim to Jeffers 4416-5K.	and P2	1341100311	J	32	19A143483P1
<b>L</b> 6	19B209420P101	Coil, RF: 100 $\mu$ h $\pm 10\%$ ; sim to Jeffers 4416-lK.				33	19A116270P1
		RESISTORS			MULTI-FREQUENCY KIT 19A130530G1	34	N330P602F22
R1	19A700106P45	Composition: 180 ohms ±5%, 1/4 w.			switches	35	19C311491P3
R2	3R151P683J	Composition: 68K ohms ±5%, 1/8 w.	sı sı	19B219515G1	Switch Assembly.	36	N55P1006
R4	3R151P101J	Composition: 100 ohms ±5%, 1/8 w.	31	13521331341		37	19C328416G1
R5	3R151P241J	Composition: 240 ohms ±5%, 1/8 w.			MISCELLANEOUS	38	19C328407P1
R7	3R151P103J	Composition: 10K ohms ±5%, 1/8 w.  Variable, cermet: 250K ohms ±10%, 1/2 w; sim to		19B216897G3	Rear Cover. (without clip).	39	19A137621P1
R8	19A116412P4	Helipot Model 62 PF.		19B216897G4	Rear Cover. (with clip).	40	19A137620P1
R9	3R151P101J	Composition: 100 ohms ±5%, 1/8 w.		19B209548P1	Antenna Assembly.	41	N207P1C6
R11	3R151P223J	Composition: 22K ohms ±5%, 1/8 w.		19D413522G4	Rechargeable Battery.	42	19B209643P2
				4038831P5	Alignment tool, fork tip.	43	19B216897G3 19B216897G4
				19B219079G1	Alignment tool, allen tip.	"	1555105707
						1	
				1			
	1		1	1		1	1

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	45	19C317394P6	Gasket.
llen wrench. (Used with No. 10 set screw or o. 5-6 socket head cap screw).	46	19B216865P1	Insulator. (Part of S702). (Not Used).
uning tool, variable capacitor. (.029 inch quare metal tip).	47	N647P5004C	Cap screw: No. 2-56 x 1/4. (Part of S702). (Not Used).
	48	19B216864P1	Contact. (Part of S702). (Not Used).
MECHANICAL PARTS (SEE RC3744)	49	19B216863P1	Spring contact. (Part of S702). (Not Used)
	50	N910P6C6	Retaining ring. (Part of S702). (Not used).
ex nut: 1/4-32.	51	19A127754P1	Gasket. (Part of S702). (Not Used).
asher, non metallic: 1/4 inch.	52	19A127755P1	Spring. (Part of S702). (Not Used).
asher, teflon: 1/4 inch.	53	19B216862P1	Contact. (Part of S702). (Not Used).
nob assembly. (Includes items 5 & 6).	54	19A127753P1	Contact. (Not Used)
et screw: No. 3-48 x 3/16. (Part of item 4).	55	19A127762P1	Strap.
nsert, tapered. (Part of item 4).	56	N330P605F22	Metallic eyelet. (Not Used).
ivet shield.	57	19B232109P1	Button plug.
ap screw, Phillips POZIDRIV®: No. 4-24 x 5/16.	58	19A130586P1	Insulator.
rille. (Used in low power only).	59	19A115794P3	Flat head screw: steel, No. 2-56 x 5/16.
rille. (Used in high power only).	60	19D413467P1	Fastener.
ase. (Includes items 7, 17, 22, 54, 56 & 62).	61	19B216891G1	Spring.
ameplate. (GE Monogram).	62	19A129723P1	Rivet.
ameplate. (GE Monogram - HI POWER).	63	19C317050P1	Protective Cover. (Not Used).
nsert.	64	19B219540P1	Catch. (Not Used).
crew, phillips head: No. 2-56 x 1/8.	65	19A129390P1	Disc. (Not Used).
ameplate. (Property of General Electric).	66	19A130426G2	Knob assembly. (Includes items 67 & 68).
hreaded insert.	67	19A130517P1	Insert. (Part of item 66).
Not Used).	68	19A143453P2	Set screw: No. 3-48 x 3/16. (Part of item 66)
ap screw: No. 4-40 x 1/4.	69	19A143880P1	washer, non metallic. (Located against hex nut item 1).
intenna tube. (Includes item 21, teflon insert).	70	19A134425P1	Machine screw, hex: No. 2-56 x 3/16.
Teflon insert.	71	19C317383P1	Dummy plug. (Not Used).
Support.	72	4033198P18	Metallic eyelet. (Not Used).
Antenna assembly.	73	19A127319P2	Nut, hex: No. 1/4-28.
Not Used).	1	1	1

Teflon insert. Support. Antenna assembly. (Not Used) Dummy plug. "0" ring.

Insulator. Strap. Gasket.

Diaphragm.

Metallic eyelet.

Dowel pin: 1/16 x 3/8.

Gasket. (Not Used).

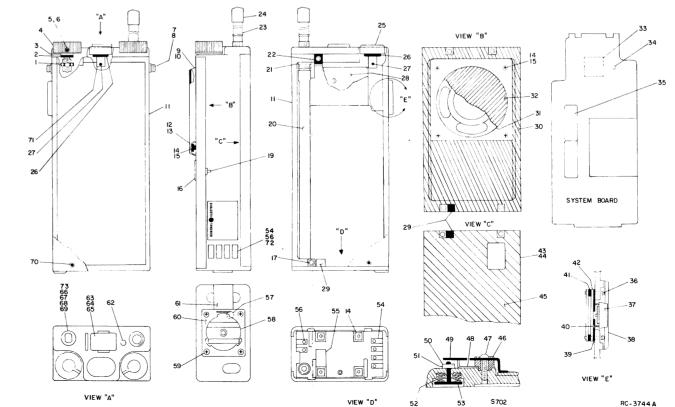
Tape, pressure sensitive. (Specify length).

Machine screw, slotted steel: No. 0-80 x 3/8 (Part of S701).

Button assembly. (Part of S701).

Collar. (Part of S701).

Plate. (Part of S701). Spring. (Part of S701). Hex nut. (Part of S701). Switch, push. (Part of S701). Rear cover assembly. (without clip). Rear cover assembly. (with clip).



## MULTI-FREQUENCY MODIFICATIONS

(19D429830, Sh. 1 Rev. 2 & Sh. 2, Rev. 0)

The multi-frequency modifications include instructions for adjusting the stop post on multi-frequency switch S1, for adding oscillator modules, for repeating frequencies, and repeating oscilla-

## I- STOP POST ADJUSTMENT

---- CAUTION ---Due to the small size of the stop posts, be very careful when making adjustments to avoid losing

- Remove the multi-frequency switch as directed in the Disassembly Procedure (See LBI-4995).
- 2. Turn the shaft fully counterclockwise as viewed from
- Unscrew the panel seal to gain access to the stop
- 4. Install the stop post in the appropriate hole as shown in the following chart.

STOP POST ADJUSTMENTS						
No. of Freq.	Move Adjustment Stop To:					
2	Н2					
3	Н3					
4	H4					
5	Н5					
6	Н6					

- 5. Replace the panel seal with the side marked "Bottom" against
- 6. Re-install the Multifrequency Switch.

## 2- ADDING OSCILLATOR MODULES

After completing the stop post adjustment, connect the leads from multi-frequency switch S1 as shown in the following chart (see Figure 3 for connection points). Tape back all unused leads.

CONNECTION CHART						
то	WIRE COLOR	S1 POSITION				
Hll (solder)	BL					
J31	₩ <b>-</b> B <b>K</b>	1				
J30	W-O	2				
Ј24	BR	3				
J25	R	4				
J26	0	5				
Ј27	Y	6				
H104	W-R	3				
H102	W-Y	4				
	TO  H11 (solder)  J31  J30  J24  J25  J26  J27  H104	TO WIRE COLOR  H11 (solder) BL  J31 W-BK  J30 W-O  J24 BR  J25 R  J26 O  J27 Y  H104 W-R				

- Place the oscillator module(s) in the proper holes (see Figure 3). Then bend over tabs on the can and solder to the adjacent pads (see Figure 2).
- Bend the leads of the oscillator module as shown in Figure 2 (or appropriate Outline Diagram) and solder to the adjacent pads.
- For two or more transmitter frequencies and one receiver frequency, remove the jumper from H7 to H10 and add a sleeved jumper (#26 AWG) from H7 to H13 on the Systems
- For two or more receiver frequencies and one transmitter frequency, remove the jumper from H8 to H10 and add a sleeved jumper (#26 AWG) from H20 and H21 on the Systems

## 3- REPEATING FREQUENCIES

For repeating both transmitter and receiver frequencies without adding additional oscillator modules, add a sleeved jumper (#26 AWG) between the frequencies to be repeated. For example, if transmitter and receiver channels 1 and 5 are to be repeated, add

## 4- REPEATING OSCILLATOR MODULES

To repeat frequencies for the transmitter only or the receiver only, diodes can be used in place of oscillator modules.

- 1. Set the stop on S1 and install the oscillator modules whose frequencies are  $\underline{\text{not}}$  to be repeated as directed in Section
- Install the oscillator(s) whose frequencies are to be repeated as directed above except solder the Number 2 pin to the "E" pad instead of the "P" pad (see Figure 2).
- 3. For every channel that a frequency is being repeated, assemble a diode 19All5100Pl in the space normally intended for the oscillator module by putting the annode lead in the Number 2 hole, bending it over and soldering to the "P" pad. The cathode lead will be terminated
- 4. For each different frequency that is repeated, an additional diode (19A115100P1) is to be assembled in respective channel closest to the oscillator module being repeated. Assemble the diode in the Number 1 hole, annode lead down and sleeved, and connect to the associated "E" pad. Then run the jumper from this pad to the "P" pad of related oscil-

The cathode end of the diodes should be connected together using mid air connections. Make the connection and run the wire down the side of the diode along the component side of the board to the next diode, and so on until all the diode's cathodes are connected together. Route these wires to give the shortest connections. Now connect a lead to the cathode of the diode that is closest to the repeated oscillator module and run this lead down the side of the diode and through any empty hole or slot to the solder side of the board, and connect the lead to the "E" pad of the oscillator module. Next, sleeve the diodes as shown in Figure 4.

Example: Channel 3 and 4 to be same as Channel 1 Channel 5 and 6 to be same as Channel 2.

- Assemble the oscillator module in Channels 1 and 2 as normal except connect the Number 2 lead to the "E" pad instead of
- 2. Assemble (1) diode in the Number 2 hole, anode lead down, in each of Channels 3, 4, 5, & 6 and solder to "P" pads.
- 3. Since two frequencies are being repeated, two additional diodes will be required, one in the Number 1 hole of Channel 3 and the other in the Number 1 hole of Channel 5 Sleeve, bend, and solder leads to the "E" pad. Connect jumper between the "E" pad of the Number 3 Channel and "P" pad of oscillator module Number 1. Connect a jumper between the "E" pad of Number 5 Channel and "P" pad of oscillator module Number 2.
- Connect the top lead (cathode) of diodes (3) in Channel 3 and 4 to each other by soldering jumper wire to leads, dressing the wire down the side of the diodes and along the board. Connect a jumper from the top of diode in the Number 1 hole of Channel 3 to the "E" pad of oscillator module Number 1. Run the wire down through the board using any available hole or slot to the solder side. Connect the jumper from the diode in Channel Number 5 to oscillator module Number 2 in the same manner.

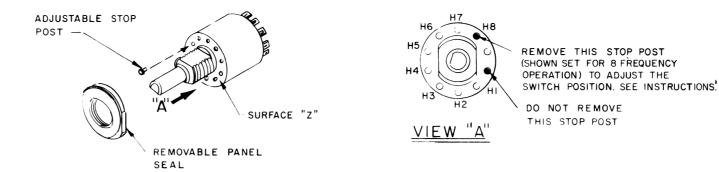


Figure 1 - Stop Post Adjusment

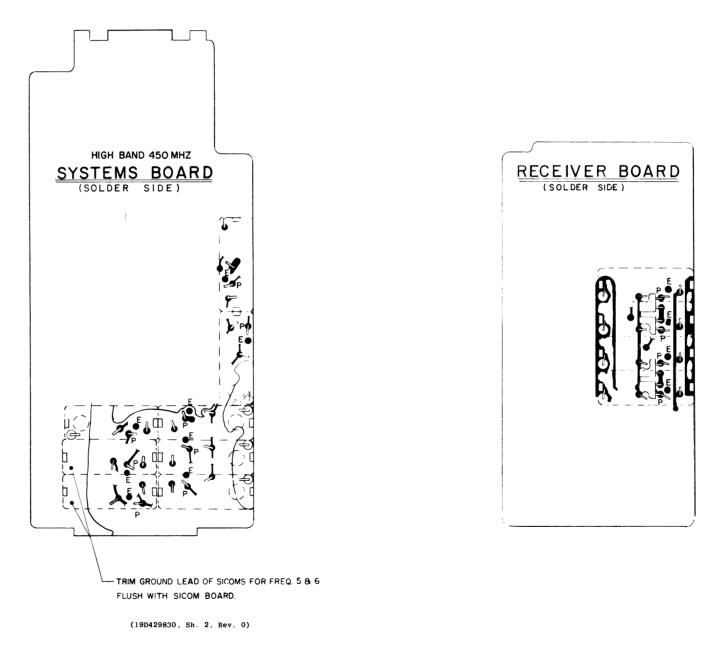


Figure 2 - Oscillator Module and Diode Installation

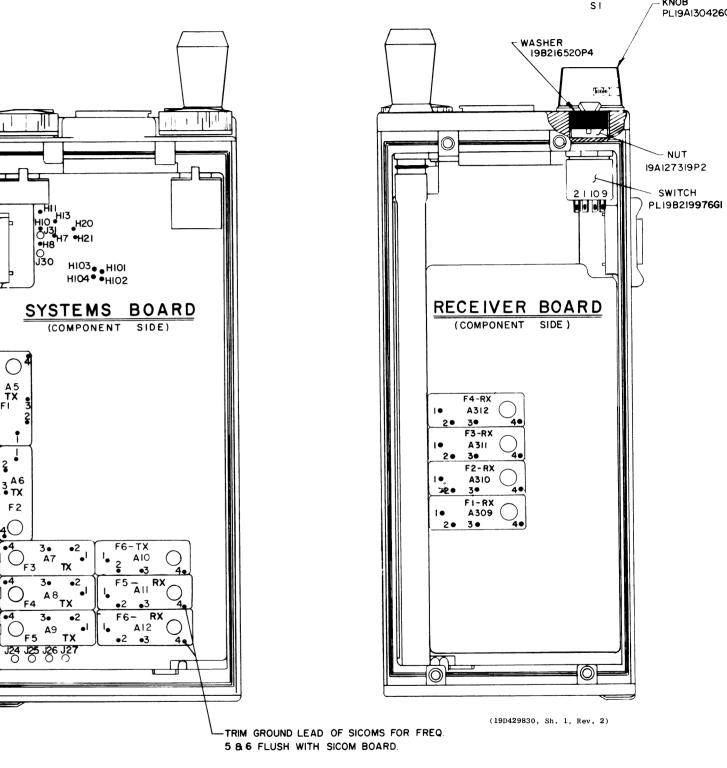
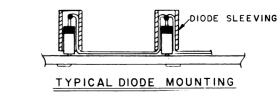


Figure 3 - Oscillator Mounting Positions & Sl Connection Points



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Figure 4 - Typical Diode Mounting

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